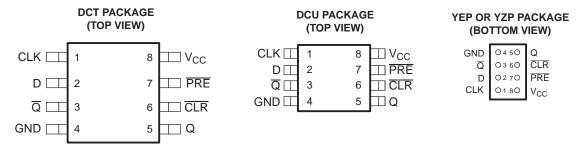
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FEATURES

- Available in the Texas Instruments
 NanoStar™ and NanoFree™ Packages
- Low Static-Power Consumption: $I_{CC} = 0.9 \mu A \text{ Max}$
- Low Dynamic-Power Consumption:
 C_{pd} = 4.3 pF Typ at 3.3 V
- Low Input Capacitance: C_i = 1.5 pF Typ
- Low Noise Overshoot and Undershoot <10% of V_{CC}
- I_{off} Supports Partial-Power-Down Mode Operation
- Schmitt-Trigger Action Allows Slow Input Transition and Better Switching Noise Immunity at the Input (V_{hys} = 250 mV Typ at 3.3 V)
- Wide Operating V_{CC} Range of 0.8 V to 3.6 V

- Optimized for 3.3-V Operation
- 3.6-V I/O Tolerant to Support Mixed-Mode Signal Operation
- t_{nd} = 4.3 ns Max at 3.3 V
- Suitable for Point-to-Point Applications
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Performance Tested Per JESD 22
 - 2000-V Human-Body Model (A114-B, Class II)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)
- ESD Protection Exceeds ±5000 V With Human-Body Model



See mechanical drawings for dimensions.

DESCRIPTION/ORDERING INFORMATION

The AUP family is Tl's premier solution to the industry's low-power needs in battery-powered portable applications. This family ensures a very low static- and dynamic-power consumption across the entire V_{CC} range of 0.8 V to 3.6 V, resulting in increased battery life (see Figure 1). This product also maintains excellent signal integrity (see the very low undershoot and overshoot characteristics shown in Figure 2).

ORDERING INFORMATION

T _A	PACKAGE ⁽¹⁾		ORDERABLE PART NUMBER	TOP-SIDE MARKING(2)
	NanoStar™ – WCSP (DSBGA) 0.23-mm Large Bump – YEP	Reel of 3000	SN74AUP1G74YEPR	HS
-40°C to 85°C	NanoFree [™] – WCSP (DSBGA) 0.23-mm Large Bump – YZP (Pb-free)	Reel of 3000	SN74AUP1G74YZPR	
	SSOP - DCT	Reel of 3000	SN74AUP1G74DCTR	H74
	VSSOP - DCU	Reel of 3000	SN74AUP1G74DCUR	H74_

Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

⁽²⁾ DCT: The actual top-side marking has three additional characters that designate the year, month, and assembly/test site.

DCU: The actual top-side marking has one additional character that designates the assembly/test site.

YEP/YZP: The actual top-side marking has three preceding characters to denote year, month, and sequence code, and one following character to designate the assembly/test site. Pin 1 identifier indicates solder-bump composition (1 = SnPb, ● = Pb-free).



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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DESCRIPTION/ORDERING INFORMATION (CONTINUED)

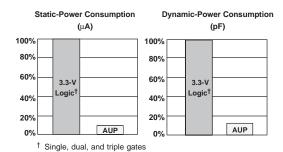


Figure 1. AUP - The Lowest-Power Family

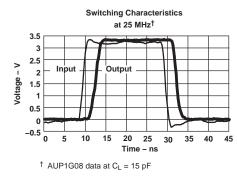


Figure 2. Excellent Signal Integrity

This single positive-edge-triggered D-type flip-flop is designed for 0.8-V to 3.6-V V_{CC} operation.

A low level at the preset (PRE) or clear (CLR) input sets or resets the outputs, regardless of the levels of the other inputs. When PRE and CLR are inactive (high), data at the data (D) input meeting the setup time requirements is transferred to the outputs on the positive-going edge of the clock pulse. Clock triggering occurs at a voltage level and is not related directly to the rise time of the clock pulse. Following the hold-time interval, data at the D input can be changed without affecting the levels at the outputs. To better optimize the flip-flop for higher frequencies, the CLR input overrides the PRE input when they are both low.

NanoStar™ and NanoFree™ package technology is a major breakthrough in IC packaging concepts, using the die as the package.

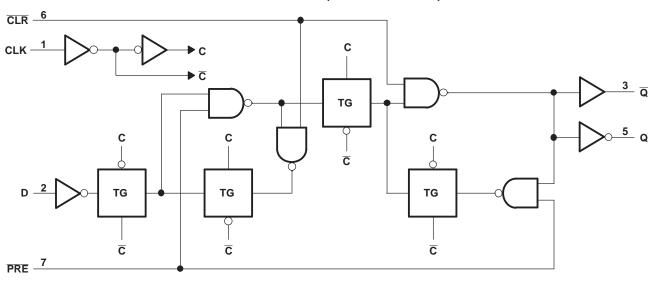
This device is fully specified for partial-power-down applications using I_{off} . The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

FUNCTION TABLE

	INP	OUT	PUTS		
PRE	CLR	CLK	D	Q	Q
L	Н	Χ	Х	Н	L
Х	L	Χ	X	L	Н
Н	Н	\uparrow	Н	Н	L
Н	Н	\uparrow	L	L	Н
Н	Н	L	Χ	Q_0	\overline{Q}_0

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LOGIC DIAGRAM (POSITIVE LOGIC)



Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CC}	Supply voltage range		-0.5	4.6	V
VI	Input voltage range ⁽²⁾		-0.5	4.6	V
Vo	Voltage range applied to any output in the h	-0.5	4.6	V	
Vo	Output voltage range in the high or low state	9(2)	-0.5	V _{CC} + 0.5	V
I _{IK}	Input clamp current	V _I < 0		-50	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
Io	Continuous output current			±20	mA
	Continuous current through V _{CC} or GND			±50	mA
		DCT package		220	
θ_{JA}	Package thermal impedance (3)	DCU package		227	°C/W
		YEP/YZP package		102	
T _{stg}	Storage temperature range		-65	150	°C

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

⁽²⁾ The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

⁽³⁾ The package thermal impedance is calculated in accordance with JESD 51-7.

SN74AUP1G74 LOW-POWER SINGLE POSITIVE-EDGE-TRIGGERED D-TYPE FLIP-FLOP



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WITH CLEAR AND PRESET

Recommended Operating Conditions⁽¹⁾

			MIN	MAX	UNIT
V _{CC}	Supply voltage		0.8	3.6	V
		V _{CC} = 0.8 V	V _{CC}		
V	Lligh lovel input veltage	V _{CC} = 1.1 V to 1.95 V	0.65 × V _{CC}		V
V_{IH}	High-level input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.6		V
		$V_{CC} = 3 \text{ V to } 3.6 \text{ V}$	2		
		V _{CC} = 0.8 V		0	
\/ 1	Low-level input voltage	V _{CC} = 1.1 V to 1.95 V		$0.35 \times V_{CC}$	V
V_{IL}	Low-level input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		0.7	V
		V _{CC} = 3 V to 3.6 V		0.9	
VI	Input voltage		0	3.6	V
Vo	Output voltage		0	V_{CC}	V
		V _{CC} = 0.8 V		-20	μΑ
	High-level output current	V _{CC} = 1.1 V		-1.1	
		V _{CC} = 1.4 V		-1.7	
I _{OH}		V _{CC} = 1.65		-1.9	mA
		V _{CC} = 2.3 V		-3.1	
		V _{CC} = 3 V		-4	
		V _{CC} = 0.8 V		20	μΑ
		V _{CC} = 1.1 V		1.1	
	Low lovel output ourrent	V _{CC} = 1.4 V		1.7	
l _{OL}	Low-level output current	V _{CC} = 1.65 V		1.9	mA
		V _{CC} = 2.3 V		3.1	
		V _{CC} = 3 V		4	
Δt/Δν	Input transition rise or fall rate	V _{CC} = 0.8 V to 3.6 V		200	ns/V
T _A	Operating free-air temperature		-40	85	°C

⁽¹⁾ All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



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Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

DADAMETED	TEST CONDITIONS	V	T,	_A = 25°C	T _A = -40°C	to 85°C	LINUT		
PARAMETER	TEST CONDITIONS	V _{CC}	MIN	TYP MAX	MIN	MAX	UNIT		
	I _{OH} = -20 μA	0.8 V to 3.6 V	V _{CC} - 0.1		V _{CC} - 0.1				
	I _{OH} = -1.1 mA	1.1 V	0.75 × V _{CC}		$0.7 \times V_{CC}$				
	$I_{OH} = -1.7 \text{ mA}$	1.4 V	1.11		1.03				
V _{OH}	$I_{OH} = -1.9 \text{ mA}$	1.65 V	1.32		1.3		V		
	$I_{OH} = -2.3 \text{ mA}$	221/	2.05		1.97				
	$I_{OH} = -3.1 \text{ mA}$	2.3 V	1.9		1.85				
	$I_{OH} = -2.7 \text{ mA}$	3 V	2.72		2.67				
	$I_{OH} = -4 \text{ mA}$	3 V	2.6		2.55				
	I _{OL} = 20 μA	0.8 V to 3.6 V		0.1		0.1			
	I _{OL} = 1.1 mA	1.1 V		$0.3 \times V_{CC}$		$0.3 \times V_{CC}$			
	I _{OL} = 1.7 mA	1.4 V		0.31		0.37			
V	I _{OL} = 1.9 mA	1.65 V		0.31		0.35	V		
V _{OL}	I _{OL} = 2.3 mA	2.3 V		0.31		0.33	V		
	I _{OL} = 3.1 mA	2.3 V		0.44		0.45			
	$I_{OL} = 2.7 \text{ mA}$	2.1/		0.31		0.33			
	I _{OL} = 4 mA	3 V		0.44		0.45			
I _I A or B input	V _I = GND to 3.6 V	0 V to 3.6 V		0.1		0.5	μΑ		
I _{off}	V_I or $V_O = 0$ V to 3.6 V	0 V		0.2		0.6	μΑ		
$\Delta I_{ m off}$	V_I or $V_O = 0$ V to 3.6 V	0 V to 0.2 V		0.2		0.6	μΑ		
Icc	$V_I = GND \text{ or } (V_{CC} \text{ to } 3.6 \text{ V}),$ $I_O = 0$	0.8 V to 3.6 V		0.5		0.9	μΑ		
ΔI_{CC}	$V_I = V_{CC} - 0.6 \ V^{(1)}, \ I_O = 0$	3.3 V		40		50	μΑ		
C	V – V or CND	0 V		1.5			nE.		
C _i	$V_I = V_{CC}$ or GND	3.6 V		1.5			pF		
C _o	V _O = GND	0 V		3			pF		

⁽¹⁾ One input at V_{CC} – 0.6 V, other input at V_{CC} or GND

SN74AUP1G74

LOW-POWER SINGLE POSITIVE-EDGE-TRIGGERED D-TYPE FLIP-FLOP WITH CLEAR AND PRESET



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Timing Requirements

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)

	PARAME	TER	V _{cc}	T _A = 25°C	T _A = -40 85°0)°C to C	UNIT
				TYP	MIN	MAX	
			0.8 V	21			
			1.2 V ± 0.1 V			40	
,	Ole als for accessor		1.5 V ± 0.1 V			50	N 41 1-
f _{clock}	Clock frequency		1.8 V ± 0.15 V			60	MHz
			2.5 V ± 0.2 V			90	
			3.3 V ± 0.3 V			90	
-			0.8 V	3.5			
			1.2 V ± 0.1 V		2		
		011/11	1.5 V ± 0.1 V		2		
		CLK high or low	1.8 V ± 0.15 V		2		
			2.5 V ± 0.2 V		2		
			3.3 V ± 0.3 V		2		
t _w	w Pulse duration		0.8 V	4.5			ns
			1.2 V ± 0.1 V		2		
			1.5 V ± 0.1 V		2		
		PRE or CLR low	1.8 V ± 0.15 V		2		
			2.5 V ± 0.2 V		2		
			3.3 V ± 0.3 V		2		
			0.8 V	3			
			1.2 V ± 0.1 V		1.3		
			1.5 V ± 0.1 V		1		
		Data high	1.8 V ± 0.15 V		1		
			2.5 V ± 0.2 V		0.5		
			3.3 V ± 0.3 V		0.5		
			0.8 V	1			
			1.2 V ± 0.1 V		1.2		
			1.5 V ± 0.1 V		1		
su	Setup time before CLK↑	Data low	1.8 V ± 0.15 V		1		ns
			2.5 V ± 0.2 V		1		
			3.3 V ± 0.3 V		1		
			0.8 V	1			
			1.2 V ± 0.1 V		0.5		
			1.5 V ± 0.1 V		0.5		
		PRE or CLR inactive	1.8 V ± 0.15 V		0.5		
			2.5 V ± 0.2 V		0.5		
			3.3 V ± 0.3 V		0.5		
		<u> </u>	0.8 V	0			
			1.2 V ± 0.1 V		0		
			1.5 V ± 0.1 V		0		
h	Hold time, data after CLK1	•	1.8 V ± 0.15 V		0		ns
		2.5 V ± 0.2 V		0			
			3.3 V ± 0.3 V		0		



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Switching Characteristics

over recommended operating free-air temperature range, $C_L = 5 \text{ pF}$ (unless otherwise noted) (see Figure 3 and Figure 4)

PARAMETER	FROM	TO (OUTPUT)	V _{cc}	T,	_\ = 25°C		T _A = -40 85°0		UNIT
	(INPUT)	(001701)		MIN	TYP	MAX	MIN	MAX	
			0.8 V		60				
			1.2 V ± 0.1 V		80		60		
			1.5 V ± 0.1 V		125		90		MHz
f _{max}			1.8 V ± 0.15 V		150		120		IVI□Z
			2.5 V ± 0.2 V		180		160		
			$3.3~\text{V}\pm0.3~\text{V}$		190		180		
			0.8 V		31				
			1.2 V ± 0.1 V	2	10	20	2.7	20.4	
		Q	1.5 V ± 0.1 V	2	6	12	1.9	12.4	
			1.8 V ± 0.15 V	2	5	9	1.4	9.5	
			$2.5~V\pm0.2~V$	2	3	6	1.1	6.2	
	0114		$3.3~\text{V}\pm0.3~\text{V}$	2	3	4	1	4.7	
	CLK		0.8 V		28				
			1.2 V ± 0.1 V	2	9	19	2.4	19	
		Q	1.5 V ± 0.1 V	2	6	11	1.6	11.8	
t _{pd}		Q	$1.8~V \pm 0.15~V$	2	5	9	1.3	9	ns
			$2.5~V\pm0.2~V$	2	3	6	1.1	6	
			$3.3~\text{V}\pm0.3~\text{V}$	2	3	4	1	4.6	
			0.8 V		26				
			1.2 V ± 0.1 V	2	9	20	2	20	
	DDE CLD	0.07	1.5 V ± 0.1 V	2	6	12	1.5	13	
	PRE OF CLR	PRE or CLR Q or Q	1.8 V ± 0.15 V	2	5	9	1.3	10	
			2.5 V ± 0.2 V	2	3	6	1	7	
			$3.3~\text{V}\pm0.3~\text{V}$	2	3	5	1	5	



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Switching Characteristics

over recommended operating free-air temperature range, $C_L = 10 \text{ pF}$ (unless otherwise noted) (see Figure 3 and Figure 4)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{cc}	T,	_{\(\)} = 25°C		T _A = -40 85°0		UNIT
	(INPOT)	(001701)		MIN	TYP	MAX	MIN	MAX	
			0.8 V		46				
			1.2 V \pm 0.1 V		65		50		
			1.5 V \pm 0.1 V		95		55		MHz
f _{max}			1.8 V \pm 0.15 V		110		60		IVITIZ
			$2.5~V\pm0.2~V$		170		130		
			3.3 V ± 0.3 V		180		160		
			0.8 V		33				
			1.2 V ± 0.1 V	2	10	22	3.4	21.8	
	OLK.	Q -	1.5 V ± 0.1 V	2	7	13	2.4	13.5	
			1.8 V ± 0.15 V	2	6	10	1.9	10.4	
			$2.5~V \pm 0.2~V$	2	4	6	1.5	7	
			$3.3~\text{V}\pm0.3~\text{V}$	2	3	5	1.2	5.3	
	CLK		0.8 V		30				
			1.2 V ± 0.1 V	2	10	20	3	20.3	
		Q	1.5 V ± 0.1 V	2	7	12	2.2	12.8	
t _{pd}		Q	1.8 V ± 0.15 V	2	5	9	1.8	9.9	ns
			$2.5~V \pm 0.2~V$	2	4	6	1.3	6.7	
			3.3 V ± 0.3 V	2	3	5	1.1	5.2	
			0.8 V		29				
			1.2 V ± 0.1 V	2	10	21	2	21.4	
	DDE CLD	0.00	1.5 V ± 0.1 V	2	7	13	2	13.8	
	PRE or CLR	R Q or Q	1.8 V ± 0.15 V	2	5	10	2	10.8	
			2.5 V ± 0.2 V	2	4	7	1.5	7.4	
			3.3 V \pm 0.3 V	2	3	5	1.5	5.8	



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Switching Characteristics

over recommended operating free-air temperature range, $C_L = 15 \text{ pF}$ (unless otherwise noted) (see Figure 3 and Figure 4)

PARAMETER	FROM	TO (OUTPUT)	V _{cc}	T,	_\ = 25°C		T _A = -40 85°0	°C to	UNIT
	(INPUT)	(OUTPUT)	33	MIN	TYP	MAX	MIN	MAX	
			0.8 V		41				
			1.2 V ± 0.1 V		75		50		
£			1.5 V ± 0.1 V		95		55		MHz
f _{max}			1.8 V ± 0.15 V		100		60		IVI□Z
			2.5 V ± 0.2 V		150		130		
			3.3 V \pm 0.3 V		200		160		
			0.8 V		35				
			1.2 V ± 0.1 V	2	12	23.1	4.1	23.2	
	OLK.	Q	1.5 V ± 0.1 V	2	8	14.1	2.9	14.6	
			1.8 V ± 0.15 V	2	6	10.7	2.4	11.3	
			$2.5 \text{ V} \pm 0.2 \text{ V}$	2	4	7	1.9	7.6	
			3.3 V \pm 0.3 V	2	4	5.4	1.6	5.9	
	CLK		0.8 V		32				
			1.2 V ± 0.1 V	2	11	21.8	3.7	21.8	
		Q	1.5 V ± 0.1 V	2	7	13.5	2.6	14	
t_{pd}		Q	$1.8~V \pm 0.15~V$	2	6	10.4	2.2	10.9	ns
			$2.5 \text{ V} \pm 0.2 \text{ V}$	2	4	7.1	1.7	7.5	
			3.3 V ± 0.3 V	2	3	5.4	1.4	5.8	
			0.8 V		31				
			1.2 V ± 0.1 V	2	11	23	2	22.9	
	DDE ** OLD	0.57	1.5 V ± 0.1 V	2	7	14	2	14.9	
	PRE or CLR	CLR Q or Q	1.8 V ± 0.15 V	2	6	11	2	11.7	
			$2.5 \text{ V} \pm 0.2 \text{ V}$	2	4	7	2	8.1	
			$3.3 \ V \pm 0.3 \ V$	2	4	6	1.5	6.4	

SN74AUP1G74

LOW-POWER SINGLE POSITIVE-EDGE-TRIGGERED D-TYPE FLIP-FLOP WITH CLEAR AND PRESET



SCES644A-MARCH 2006-REVISED SEPTEMBER 2006

Switching Characteristics

over recommended operating free-air temperature range, $C_L = 30 \text{ pF}$ (unless otherwise noted) (see Figure 3 and Figure 4)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC}	T,	(= 25°C		T _A = -40°C to 85°C		UNIT
	(INPOT)	(001701)		MIN	TYP	MAX	MIN	MAX	
			0.8 V		21				
			1.2 V ± 0.1 V		50		40		
			1.5 V ± 0.1 V		60		50		MHz
f _{max}			1.8 V ± 0.15 V		75		70		IVI□Z
			2.5 V ± 0.2 V		100		90		
			3.3 V ± 0.3 V		100		90		
			0.8 V		32				
			1.2 V ± 0.1 V	3	14	27	5.9	27	
	CLK	Q	1.5 V ± 0.1 V	3	10	17	4.4	17.2	
			1.8 V ± 0.15 V	3	8	13	3.6	13.4	
			2.5 V ± 0.2 V	3	6	9	3	9.2	
			3.3 V \pm 0.3 V	3	5	7	2.6	7.2	
			0.8 V		40				
			1.2 V ± 0.1 V	3	13	26	5.5	25.9	
		Q	1.5 V ± 0.1 V	3	9	16	4.1	16.8	
t _{pd}		Q	1.8 V ± 0.15 V	3	7	13	3.5	13.2	ns
			2.5 V ± 0.2 V	3	5	9	2.7	9.2	
			$3.3~\text{V}\pm0.3~\text{V}$	3	5	7	2.4	7.2	
			0.8 V		38				
			1.2 V ± 0.1 V	3	13	26	3	27	-
	DDE CLD	0.55	1.5 V ± 0.1 V	3	9	17	3	17.4	
	PRE OF CLR	RE or CLR Q or Q	1.8 V ± 0.15 V	3	8	13	3	14	
			2.5 V ± 0.2 V	3	6	9	3	10	
			$3.3~\text{V}\pm0.3~\text{V}$	3	5	7	2.5	8	

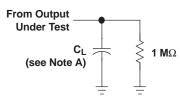
Operating Characteristics

 $T_A = 25^{\circ}C$

	PARAMETER	TEST CONDITIONS	V _{cc}	TYP	UNIT
			0.8 V	5.5	
		f = 10 MHz	1.2 V ± 0.1 V	5.5	~F
_	Dower dissination conscitance		1.5 V ± 0.1 V	5.5	
C _{pd}	Power dissipation capacitance		1.8 V ± 0.15 V	5.5	pF
			$2.5~V\pm0.2~V$	5.5	
			3.3 V ± 0.3 V	5.5	

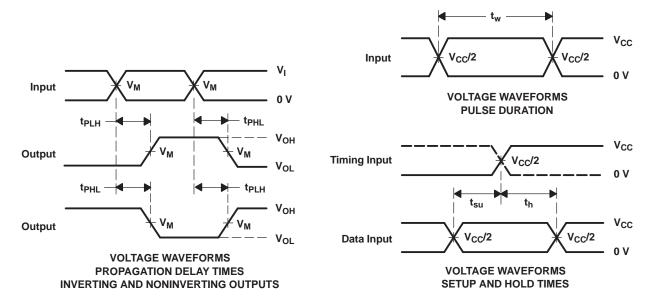
SCES644A-MARCH 2006-REVISED SEPTEMBER 2006

PARAMETER MEASUREMENT INFORMATION (Propagation Delays, Setup and Hold Times, and Pulse Width)



LOAD CIRCUIT

	V _{CC} = 0.8 V	V _{CC} = 1.2 V ± 0.1 V	V _{CC} = 1.5 V ± 0.1 V	V _{CC} = 1.8 V ± 0.15 V	V_{CC} = 2.5 V \pm 0.2 V	V _{CC} = 3.3 V ± 0.3 V
CL	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF
V _M	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2
VI	V _{CC}	V _{CC}	V _{CC}	V _{CC}	V _{CC}	V _{CC}



NOTES: A. C₁ includes probe and jig capacitance.

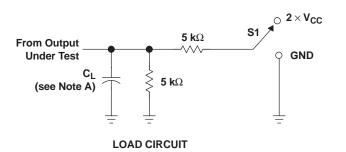
- B. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, $t_f/t_f = 3 \text{ ns}$.
- C. The outputs are measured one at a time, with one transition per measurement.
- D. t_{PLH} and t_{PHL} are the same as t_{pd} .
- E. All parameters and waveforms are not applicable to all devices.

Figure 3. Load Circuit and Voltage Waveforms

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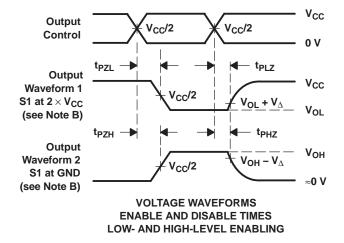


PARAMETER MEASUREMENT INFORMATION (Enable and Disable Times)



TEST	S 1
t _{PLZ} /t _{PZL}	$2\times\mathbf{V_{CC}}$
t _{PHZ} /t _{PZH}	GND

 $V_{CC} = 1.2 V$ $V_{CC} = 1.5 \overline{V}$ $V_{CC} = 1.8 \overline{V}$ $V_{CC} = 2.5 V$ $V_{CC} = 3.3 \overline{V}$ $V_{CC} = 0.8 V$ \pm 0.1 V \pm 0.1 V \pm 0.15 V \pm 0.2 V \pm 0.3 V 5, 10, 15, 30 pF C_L 5, 10, 15, 30 pF \mathbf{v}_{M} V_{CC}/2 V_{CC}/2 V_{CC}/2 V_{CC}/2 V_{CC}/2 V_{CC}/2 ν_{CC} v_{cc} v_{cc} ν_{CC} ٧ı v_{cc} V_{CC} V_{Δ} 0.1 V 0.1 V 0.1 V 0.15 V 0.15 V 0.3 V



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, $t_r/t_f = 3$ ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en} .
- G. All parameters and waveforms are not applicable to all devices.

Figure 4. Load Circuit and Voltage Waveforms





.com 12-Sep-2006

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins P	ackage Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
SN74AUP1G74DCUR	ACTIVE	US8	DCU	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUP1G74DCURG4	ACTIVE	US8	DCU	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

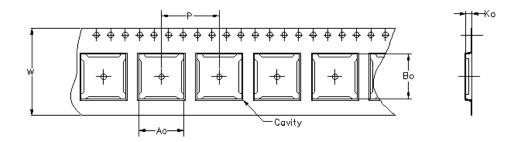
Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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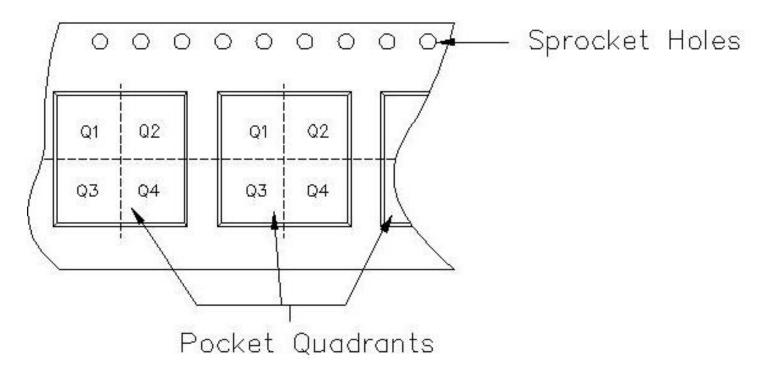
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Carrier tape design is defined largely by the component lentgh, width, and thickness.

Ao =	Dimension	designed	to	accommodate	the	component	width.	
Bo =	Dímension	designed	to	accommodate	the	component	length.	
Ko =	Dímension	designed	to	accommodate	the	component	thickness.	
W = Overall width of the carrier tape.								
P = Pitch between successive cavity centers.								

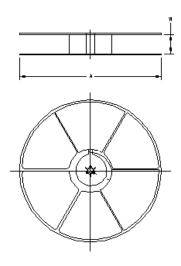


TAPE AND REEL INFORMATION



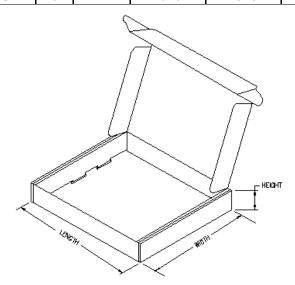
19-May-2007

Device	Package	Pins	Site	Reel Diameter (mm)	Reel Width (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AUP1G74DCUR	DCU	8	HNT	180	9	2.25	3.35	1.05	4	8	NONE



TAPE AND REEL BOX INFORMATION

Device		Package	Pins	Site	Length (mm)	Width (mm)	Height (mm)
	SN74AUP1G74DCUR	DCU	8	HNT	202.0	201.0	28.0



DCU (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE (DIE DOWN)



NOTES:

- : A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
 - D. Falls within JEDEC MO-187 variation CA.



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